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September 2016

GreenBridge[™] 2 Series of High-Efficiency Bridge Rectifiers

Features

- Low Power Loss GreenBridgeTM Replaces Diode Bridge
- Self Driving Circuitry for MOSFETs
- Low r_{DS(on)} 80V Rated MOSFETs
- Maximizing Available Power and Voltage
- Eliminating Thermal Design Problems
- IEEE802.3at Compatible
 - Meet Detection and Classification Requirement
 - Work with 2 and 4-pair Architecture
 - Small Backfeed Voltage
- Compact MLP 4.5x5 Package

Applications

- Power over Ethernet (PoE) Power Device (PD)
 - IP Phones
 - Network Cameras
 - Wireless Access Points
 - Thin Clients
 - Microcell
 - Femtocell

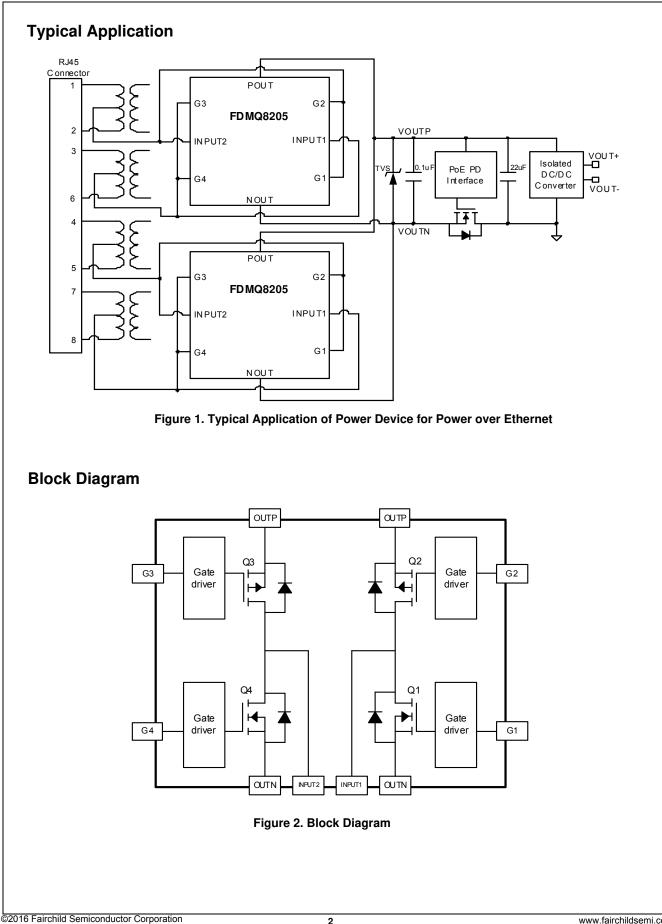
General Description

FDMQ8205 is GreenBridgeTM2 series of quad MOSFETs for a bridge application so that the input will be insensitive to the polarity of a power source coupled to the device. Many known bridge rectifier circuits can be configured using typical diodes. The conventional diode bridge has relatively high power loss that is undesirable in many applications. Especially, Power over Ethernet (PoE) Power Device (PD) application requires high-efficiency bridges because it should be operated with the limited power delivered from Power Source Equipment (PSE) which is classified by IEEE802.3at. FDMQ8205 is configured with low $r_{DS(on)}$ dual P-ch MOSFETs and N-ch MOSFETs so that it can reduce the power loss caused by the voltage drop, compared to the conventional diode bridge. FDMQ8205 enables the application to maximize the available power and voltage and to eliminate the thermal design problems in PoE PD applications.

FDMQ8205 GreenBridgeTM2 is compatible with IEEE802.3at PoE standard by not compromising detection and classification requirement as well as small backfeed voltage.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMQ8205	FDMQ8205	MLP4.5x5	13 "	12 mm	3000 units



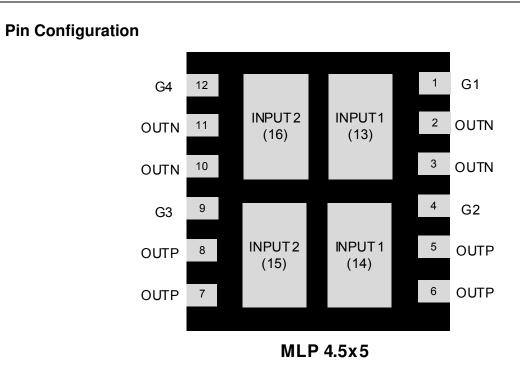


Figure 3. Pin Assignment (Bottom View)

Pin Descriptions

Pin Number	Name	Description
1	G1	Gate of Q1 N-ch MOSFET
4	G2	Gate of Q2 P-ch MOSFET
9	G3	Gate of Q3 P-ch MOSFET
12	G4	Gate of Q4 N-ch MOSFET
13,14	INPUT1	Input1 of GreenBridge TM
15,16	INPUT2	Input2 of GreenBridge TM
2,3,11,10	OUTN	Negative Output of GreenBridge TM
5,6,7,8	OUTP	Positive Output of GreenBridge TM

Notes:

1. Show the feature that provides orientation or pin 1 location.

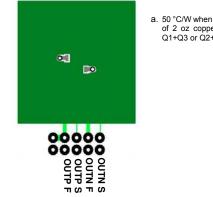
Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

			Min.	Max.	Units
INPUT1, INPUT2 to OUTN				80	V
OUTP to IN	PUT1, INPUT2			80	V
INPUT1	to INPUT2			80	V
INPUT2	to INPUT1			80	V
OUTP	to OUTN			80	V
G1, G2, G3, G4 to OUTN				70	V
OUTP to G1, G2, G3, G4				70	V
V _{G_TRANSIENT}	Transient Gate Voltage, Pulse W Duty Cycle < 0.003			100	V
Continuous I _{INPUT} (GreenBridge TM Current,	T _A = 25 °C	(Note 2a)		3.0	А
Q1+Q3 or Q2+Q4)	T _A = 25 °C	(Note 2b)		1.7	А
Pulsed I _{INPUT} (Q1+Q3 or Q2+Q4)	Pulse Width < 300 μs, Duty Cycle	e < 2% (Note 3)		58	А
P. (Power Dissinction, 01, 02, or 02, 04)	T _A = 25 °C	(Note 2a)		2.5	W
P _D (Power Dissipation, Q1+Q3 or Q2+Q4)	T _A = 25 °C	(Note 2b)		0.78	W
Max Junction Temperature				150	°C

Notes :

2. $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a. 50 °C/W when mounted on a 1 in² pad of 2 oz copper, the board designed Q1+Q3 or Q2+Q4.



b. 160 °C/W when mounted on a minimum pad of 2 oz copper, the board designed Q1+Q3 or Q2+Q4.

3. Pulse Id measured at td <= 300µs, refer to SOA graph for more details.

Thermal Characteristics

Symbol	Parameter		Min.	Тур.	Max.	Units
R_{\thetaJC}	Thermal Resistance, Junction to Case			5.1		
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 2a)		50		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 2b)		160		

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Max.	Units
V _{INPUT}	Input Voltage of Bridge	INPUT1 to INPUT2 or INPUT2 to INPUT1		57	V
V _G	Gate Voltage of MOSFETs	G1, G4 to OUTN G2, G3 to OUTP		57	V
I _{INPUT}	Input Current of Bridge	Bridge Current through Q2 and Q4 or (Q3 and Q1)		1.7	А
	Ambient Operation Temperature (T _A)			85	°C
	Junction Operating Temperature (T _J) (Note 5)			125	°C

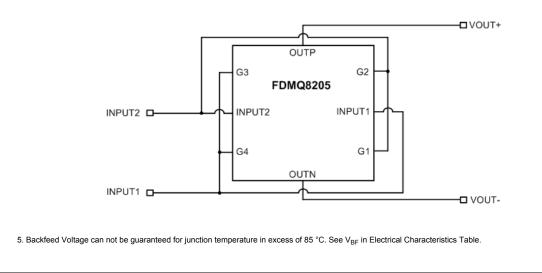
Electrical Characteristics

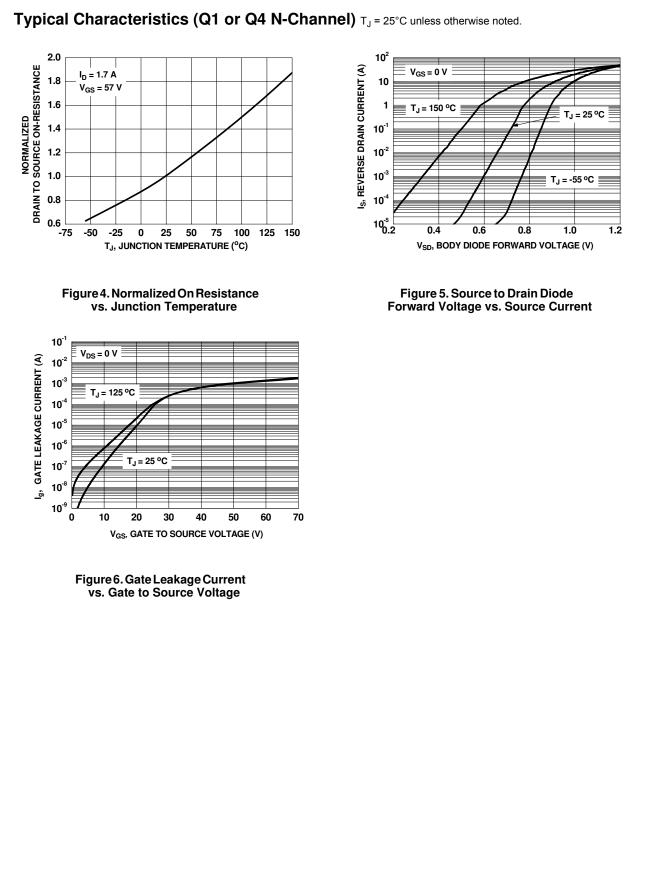
Unless otherwise noted: $T_J = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{INPUT}	Input Voltage of Bridge	At INPUT1 to INPUT2 or INPUT2 to INPUT1			57	V
V _G	Gate Voltage of MOSFETs	At G1, G4 to OUTN and G2, G3 to OUTP			57	V
IQ	Quiescent Current	Detection Mode 1.5 V $<$ V _{INPUT} =V _G $<$ 10.1V (Note 4)			5	μA
		Classification Mode 10.2 V $<$ V _{INPUT} =V _G $<$ 23.9 V (Note 4)			400	μA
		Power On Mode Maximum $V_{INPUT}=V_G=57 V$ (Note 4)			3.2	mA
V _{TURN_ON}	Turn-On Voltage of MOSFETs	Turn-On of MOSFETs while V_G Increases (Note 4)	32		36	V
I _{LEAKAGE}	Turn-Off Leakage Current	V_{OUTP} =57 V, V_{OUTN} =0 V T _J = -40 °C to 85 °C (Note 4)			700	μA
V_{BF}	Backfeed Voltage	V_{OUTP} =57 V, V_{OUTN} =0 V, 100 kOhm between INPUT1 and INPUT2 T_{J} = -40 °C to 85 °C (Note 4)			2.7	V
		V _G =42 V, I _{INPUT} =1.5 A, T _A =25 °C		35	51	mΩ
	N-ch MOSFET	V _G =48 V, I _{INPUT} =1.5 A, T _A =25 °C		29	44	mΩ
r _{DS(on)}		V _G =57 V, I _{INPUT} =1.5 A, T _A =25 °C		26	37	mΩ
		V _G = -42 V, I _{INPUT} = -1.5 A, T _A =25 °C		95	147	mΩ
	P-ch MOSFET	V _G = -48 V, I _{INPUT} = -1.5 A, T _A =25 °C		83	125	mΩ
		V _G = -57 V, I _{INPUT} = -1.5 A, T _A =25 °C		76	107	mΩ

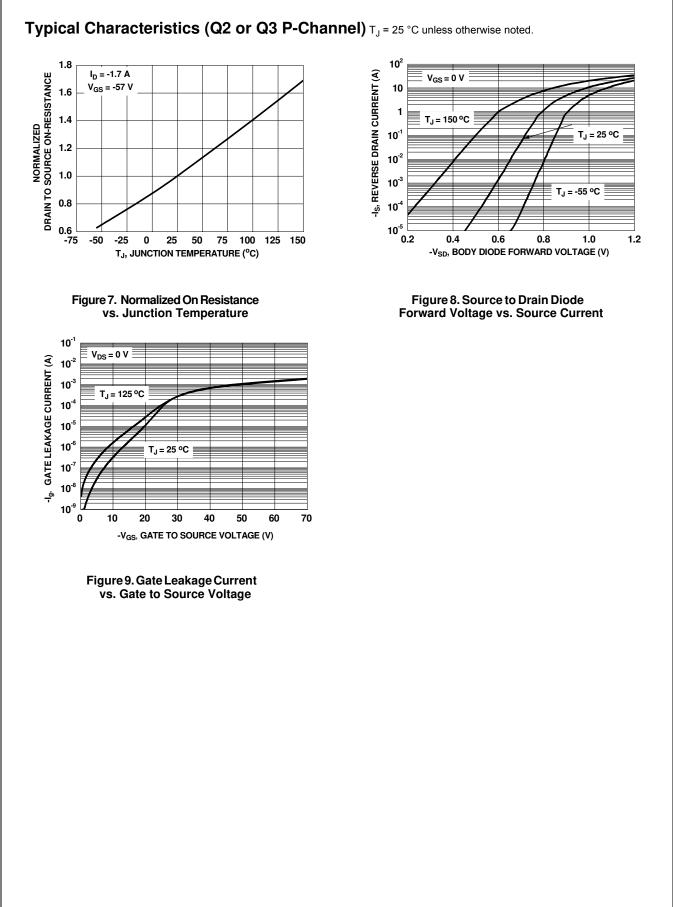
Notes:

4. INPUT1 is connected to G3 and G4 and also INPUT2 is connected to G1 and G2 like below.

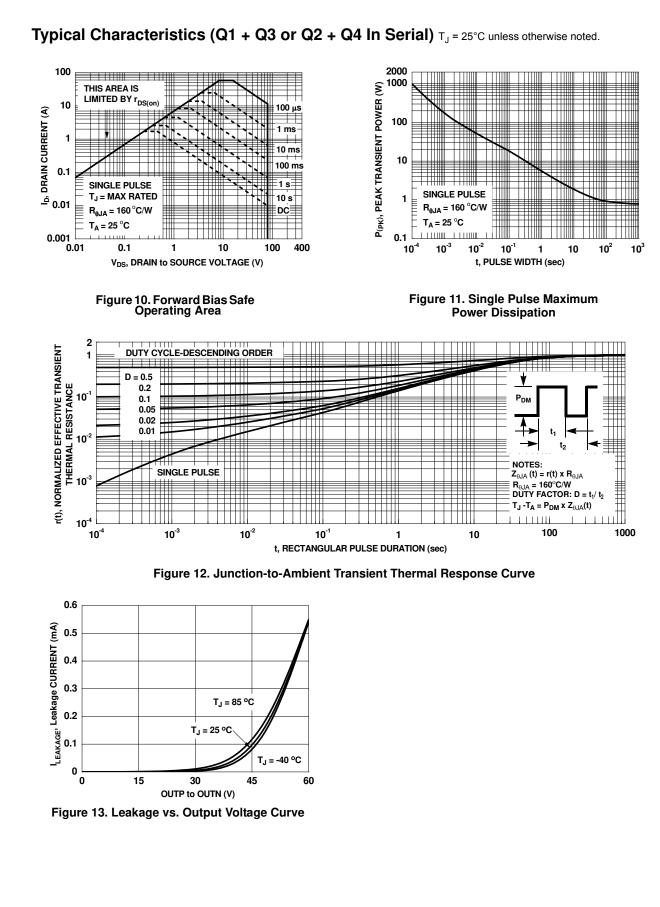


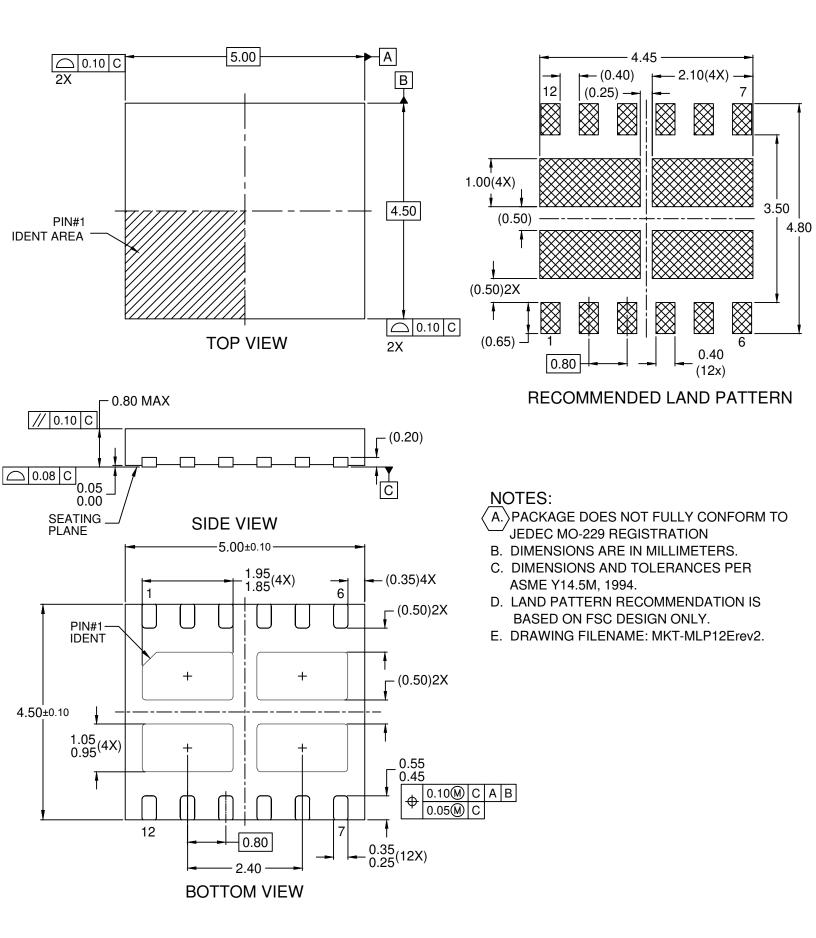


FDMQ8205 - GreenBridgeTM2 Series of High-Efficiency Bridge Rectifiers



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